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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## Polar ${ }^{\text {TM }} \mathrm{HiPerFET}^{\text {TM }}$ Power MOSFET

## N-Channel Enhancement Mode

Avalanche Rated
Fast Intrinsic Rectifier


| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {Dss }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 600 | V |
| $\mathrm{V}_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{GS}}=1 \mathrm{M} \Omega$ | 600 | V |
| $\mathrm{V}_{\text {Gss }}$ | Continuous | $\pm 30$ | V |
| $\mathrm{V}_{\text {GSM }}$ | Transient | $\pm 40$ | V |
| $\mathrm{I}_{\mathrm{D} 25}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 10 | A |
| $\underline{\mathrm{I}_{\text {M }}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ | 25 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 10 | A |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 500 | mJ |
| dv/dt | $\mathrm{I}_{\mathrm{S}} \leq \mathrm{I}_{\mathrm{DM}}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\mathrm{DSS}}, \mathrm{T}_{\mathrm{J}} \leq 150^{\circ} \mathrm{C}$ | 10 | V/ns |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 200 | W |
| TJ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{JM}}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{O}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062in.) from Case for 10 s | 300 | ${ }^{\circ} \mathrm{O}$ |
| $\mathrm{T}_{\text {sold }}$ | Plastic Body for 10 Seconds | 260 | ${ }^{\circ} \mathrm{C}$ |
| $M_{\text {d }}$ | Mounting Torque (TO-220) | 1.13 / 10 | Nm/lb.in. |
| Weight | TO-263 | 2.5 | g |
|  | TO-220 | 3.0 | g |



| $\mathrm{V}_{\text {oss }}=600 \mathrm{~V}$ |
| :---: |
| $=10 \mathrm{~A}$ |
| $\leq 74$ |
| $\leq 200$ |

TO-263 AA (IXFA)


TO-220AB (IXFP)

$\mathrm{G}=$ Gate $\quad \mathrm{D}=$ Drain

## Features

- International Standard Packages
- Dynamic dv/dt Rating
- Avalanche Rated
- Fast Intrinsic Rectifier
- Low $Q_{G}$
- Low $\mathrm{R}_{\mathrm{DS}(\text { on })}$
- Low Drain-to-Tab Capacitance
- Low Package Inductance


## Advantages

- Easy to Mount
- Space Savings


## Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- Uninterrupted Power Supplies
- AC Motor Drives
- High Speed Power Switching Applications



## Source-Drain Diode

Symbol Test Conditions

| ( $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$, Unless Otherwise Specified) |  | Min. ${ }^{\text {T }}$ Typ. | Max. |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{s}}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  | 10 | A |
| $I_{\text {SM }}$ | Repetitive, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ |  | 30 | A |
| $\mathrm{V}_{\text {SD }}$ | $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{S}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$, Note 1 |  | 1.5 | V |
| $\left.\begin{array}{l} \mathrm{t}_{\mathrm{rr}} \\ \mathrm{I}_{\mathrm{RM}} \\ \mathrm{Q}_{\mathrm{RM}} \end{array}\right\}$ | $\begin{aligned} & I_{F}=0.5 \cdot I_{D 25}, V_{G S}=0 V \\ & -d i / d t=100 \mathrm{~A} / \mu \mathrm{S} \\ & V_{R}=100 \mathrm{~V} \end{aligned}$ | $\begin{array}{r} 120 \\ 3 \\ 320 \end{array}$ | 200 | ns A nC |

Notes: 1. Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle, $\mathrm{d} \leq 2 \%$.
2. On through-hole packages, $\mathrm{R}_{\mathrm{DS}(\text { (n) }}$ Kelvin test contact location must be 5 mm or less from the package body.

TO-263 Outline


| SYM | INCHES |  | MILLIMETERS |  |
| :--- | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | .160 | .190 | 4.06 | 4.83 |
| A1 | .080 | .110 | 2.03 | 2.79 |
| b | .020 | .039 | 0.51 | 0.99 |
| b2 | .045 | .055 | 1.14 | 1.40 |
| c | .016 | .029 | 0.40 | 0.74 |
| c2 | .045 | .055 | 1.14 | 1.40 |
| D | .340 | .380 | 8.64 | 9.65 |
| D1 | .315 | .350 | 8.00 | 8.89 |
| E | .380 | .410 | 9.65 | 10.41 |
| E1 | .245 | .320 | 6.22 | 8.13 |
| e | .100 BSC | 2.54 BSC |  |  |
| L | .575 | .625 | 14.61 | 15.88 |
| L1 | .090 | .110 | 2.29 | 2.79 |
| L2 | .040 | .055 | 1.02 | 1.40 |
| L3 | .050 | .070 | 1.27 | 1.78 |
| L4 | 0 | .005 | 0 | 0.13 |

## TO-220 Outline



| SYM | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | .170 | .190 | 4.32 | 4.83 |
| b | .025 | .040 | 0.64 | 1.02 |
| b1 | .045 | .065 | 1.15 | 1.65 |
| c | .014 | .022 | 0.35 | 0.56 |
| D | .580 | .630 | 14.73 | 16.00 |
| E | .390 | .420 | 9.91 | 10.66 |
| e | .100 BSC |  | 2.54 BSC |  |
| F | .045 | .055 | 1.14 | 1.40 |
| H1 | .230 | .270 | 5.85 | 6.85 |
| J1 | .090 | .110 | 2.29 | 2.79 |
| k | 0 | .015 | 0 | 0.38 |
| L | .500 | .550 | 12.70 | 13.97 |
| L1 | .110 | .230 | 2.79 | 5.84 |
| $\varnothing P$ | .139 | .161 | 3.53 | 4.08 |
| Q | .100 | .125 | 2.54 | 3.18 |

Fig. 1. Output Characteristics $@ \mathrm{~T}_{\mathrm{J}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$


Fig. 3. Output Characteristics @ $\mathrm{T}_{\mathbf{J}}=\mathbf{1 2 5}{ }^{\circ} \mathrm{C}$


Fig. 5. $\mathrm{R}_{\mathrm{DS}(o n)}$ Normalized to $\mathrm{I}_{\mathrm{D}}=5 \mathrm{~A}$ Value vs.
Drain Current


Fig. 2. Extended Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$


Fig. 4. $R_{D S(o n)}$ Normalized to $I_{D}=5 A$ Value vs. Junction Temperature


Fig. 6. Maximum Drain Current vs.
Case Temperature


Fig. 7. Input Admittance


Fig. 9. Forward Voltage Drop of Intrinsic Diode


Fig. 11. Capacitance


Fig. 8. Transconductance


Fig. 10. Gate Charge


Fig. 12. Maximum Transient Thermal Impedance


IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

